

Features

- Low R_{DS(on)} & FOM
- · Extremely Low Switching Loss
- · Excellent Stability and Uniformity
- · Fast Switching and Soft Recovery
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1

Maximum Ratings

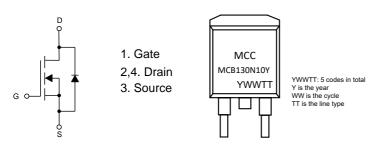
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 62°C/W Junction to Ambient⁽¹⁾
- Thermal Resistance: 0.65°C/W Junction to Case

Parameter	Symbol	Value
Drain-Source Voltage	V _{DS}	100V
Gate-Source Volltage	V_{GS}	±20V
Continuous Drain Current ⁽²⁾ ,T _C =25°C	I _D	130A
Pulsed Drain Current ⁽³⁾ , T _C =25°C	I _{D,pluse}	390A
Power Dissipation ⁽⁴⁾ , T _C =25°C	P _D	192W
Single Pulsed Avalanche Energy ⁽⁵⁾	E _{AS}	500mJ

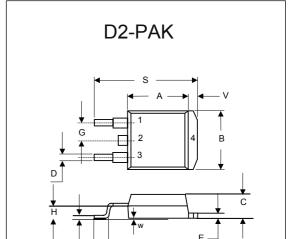
Note:

- 1. The Value of $R_{\theta JA}$ is Measured with the Device Mounted on 1 in² FR-4 Board with 2oz. Copper, In a Still Air Environment with T_A =25°C.
- 2. Calculated Continuous Current Based on Maximum Allowable Junction Temperature.
- 3. Repetitive Rating: Pulse Width Limited By Max. Junction Temperature.
- 4. Pd is Based on Max. Junction Temperature, Using Junction-Case Thermal Resistance.
- 5. V_{DD} =50V, R_G =25 Ω , L=0.5mH, Starting T_J =25 $^{\circ}$ C.

Internal Structure and Marking Code

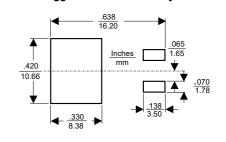


N-Channel MOSFET



DIMENSIONS					
DIM		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.331	0.370	8.40	9.40	
В	0.378	0.417	9.60	10.60	
С	0.165	0.189	4.20	4.80	
D	0.027	0.037	0.68	0.94	
Е	0.045	0.055	1.14	1.40	
G	0.010		2.54		TYP.
Н	0.096	0.134	2.43	3.40	
J	0.011	0.025	0.28	0.64	
K	0.071	0.131	1.80	3.32	
S	0.575	0.625	14.60	15.87	
V	0.042	0.058	1.07	1.47	
W	0.000	0.010	0.00	0.25	

Suggested Solder Pad Layout

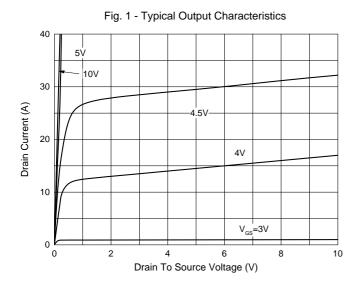


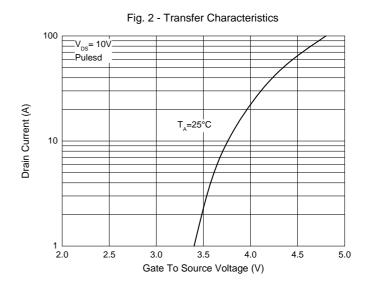


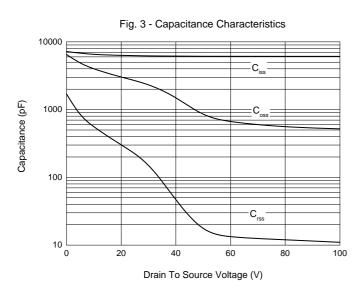
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics			l .			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1.2	2	4	V
Gate-Body Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =60A		4.0	4.6	mΩ
Dynamic Characteristics			l .			
Drain-Source On-Voltage	C _{iss}			6124.6		pF
Output Capacitance	C _{oss}	V _{GS} =0V,V _{DS} =50V,f=1MHz		792.3		pF
Reverse Transfer Capacitance	C _{rss}			15.1		pF
Turn-On Delay Time	t _{d(on)}			28.2		ns
Rise Time	t _r	V_{GS} =10V, V_{DS} =50V, R_{G} =2.2 Ω , I_{D} =22 A		7.5		ns
Turn-Off Delay Time	t _{d(off)}			81.9		ns
Fall Time	t _f			20.1		ns
Gate Charge Characteristics			I			
Total Gate Charge	Qg			101.6		nC
Gate-Source Charge	Q _{gs}	I _D =22A,V _{DS} =50V,V _{GS} =10V		20.6		nC
Gate-Drain Charge	Q _{gd}	1D-22A, VDS-30V, VGS-10V		28.7		nC
Gate Plateau Voltage	V _{plateau}			4.2		V
Body Diode Characteristics				-		
Diode Forward Current	Is	V - N			130	Α
Pulsed Source Current	I _{SP}	V_{GS} < V_{th}			390	Α
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V			1.3	V
Reverse Recovery Time	t _{rr}			82.1		ns
Reverse Recovery Charge	Q _{rr}	I_S =10A,di/dt=100A/ μ s		248.4		nC
Peak Reverse Recovery Current	I _{rrm}			4.9		Α

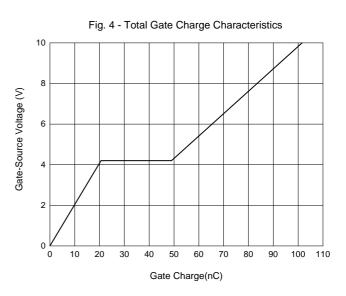


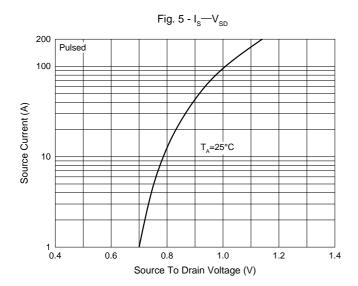
Curve Characteristics

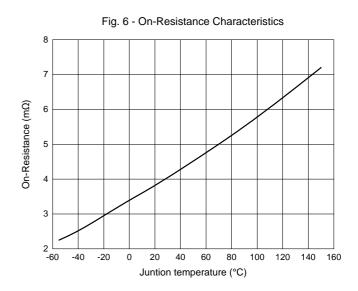














Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 800pcs/Reel	
Part Number-BP	Tube: 5Kpcs/Ctn	

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

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